



N-Channel 20V (D-S) Power MOSFET

Features

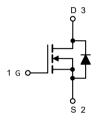
- 150°C operating temperature
- Halogen Free, Pb-Free
- RoHS Compliant



SOT-23

Applications

- Relay driver
- Switching circuits
- High-side load switch
- High-speed line driver



Absolute Maximum Ratings (T _A =25°C unless otherwise noted)					
Parameter	Symbol	Value	Unit		
Drain Source Voltage	V _{DS}	20	V		
Gate Source Voltage	V _G s	±20	V		
Drain Current, Continuous V _{GS} =10V			3	Α	
Drain Current, Pulsed (Note 1)	I _{DM}	11	Α		
Power Dissipation T _C =25°C		P _D	1.4	W	
Operating Junction/ Storage Tempera	T _J / T _{STG}	-55 to +150	°C		

Note 1: Single pulse; $t_p \le 1$ us.

Thermal Characteristics				
Parameter	Symbol	Max	Unit	
Thermal Resistance Junction to Ambient (Note 2)	R _{thJA}	140	°C/W	

Note 2: Device mounted on 1 square inch FR4 PCB board, with 2oz single-sided copper, in a 25°C still air environment.



Electrical Characteristics (T _A =25°C unless otherwise noted)						
Parameter	Symbol	Test Conditions	Min	Тур	Max	Unit
Drain Source Breakdown Voltage	V _{(BR)DSS}	V _{GS} =0V, I _D =250µA	20			V
Zero Gate Voltage Drain Current	I _{DSS}	V _{DS} =20V, V _{GS} =0V			1	uA
Gate Threshold Voltage	V _{GS(TH)}	V _{DS} =V _{GS} , I _{DS} =250uA	0.4		1	V
Gate Leakage Current	I _{GSS}	V _{GS} =±12V, V _{DS} =0V			±100	nA
Drain-Source On-state Resistance (Note 3)	_	V _{GS} =4.5V, I _D =2A		44	55	mΩ
	R _{DS(on)}	V _{GS} =2.5V, I _D =1A		52	80	
Total Gate Charge	Qg			10		nC
Gate-Source Charge	Qgs	$V_{GS(off)}=0V, V_{GS(on)}=4.5V, V_{Ds}=10V, I_{D}=4.2A$		2.3		
Gate-Drain Charge	Q_{gd}	, -		2.9		
Turn-on Delay Time	t _{d(on)}			3.6		
Turn-on Rise Time	tr	V_{GS} =4.5V, V_{DD} =20V,		10.6		
Turn-off Delay Time	t _{d(off)}	$R_L=10\Omega$, $R_G=3\Omega$		7.2		ns
Turn-off Fall Time	t _f			4		
Input Capacitance	Ciss			133		
Output Capacitance	Coss	V _{GS=} 0V, V _{DS} =20V, f=1MHz		24		pF
Reverse Transfer Capacitance	C _{rss}			17		

Reverse Diode Characteristics (T _A =25°C unless otherwise noted)						
Parameter	Symbol	Test Conditions	Min.	Тур.	Max.	Unit
Forward Current, Continuous	I _{SD}	T _C =25°C			3	Α
Diode Forward Voltage (Note 3)	V _{SD}	I _F =1A, V _{GS} =0V			1.2	V

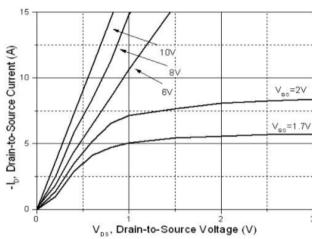
Note 3: Pulse test; pulse width ≤ 380µs, duty cycle ≤ 1%.

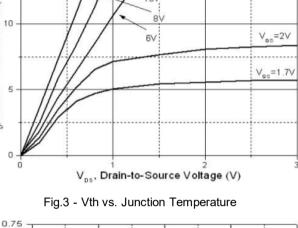




Typical Characteristics Curves (T_A = 25°C unless otherwise noted)

Fig.1 - Output Characteristics





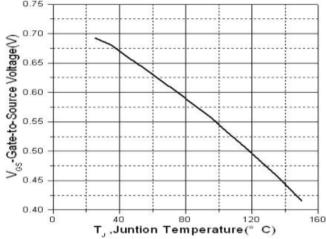


Fig.5 - Drain Current vs. Case Temperature

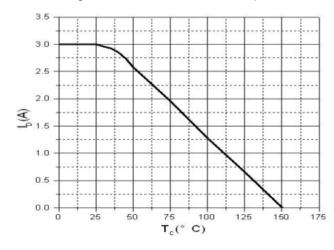


Fig.2 - RDS(on) vs. Junction Temperature

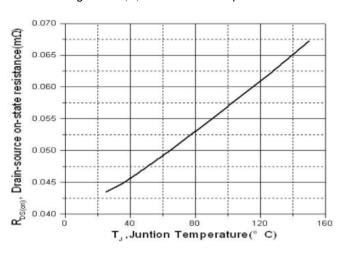


Fig.4 - Capacitance

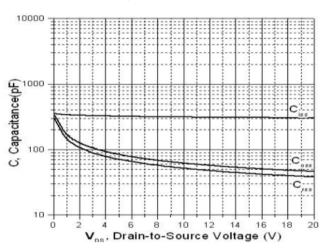
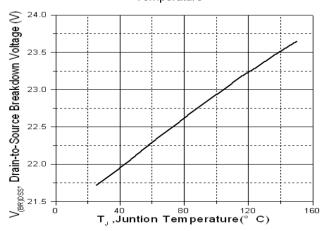


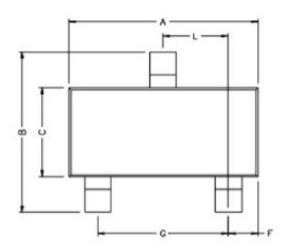
Fig.6 - Drain-to-Source Breakdown Voltage vs. Junction Temperature

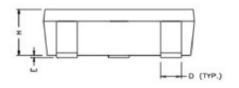


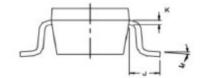


Package Outline Dimensions (Unit: millimeters)

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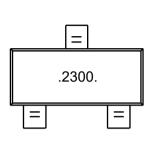


DEE Millin		meter	DEE	Millimete		
REF.	Min.	Max.	REF.	Min.	Max.	
Α	2.80	3.00	G	1.80	2.00	
В	2.30	2.50	Н	0.90	1.1	
C	1.20	1.40	K	0.10	0.20	
D	0.30	0.50	J	0.35	0.70	
E	0	0.10	L	0.92	0.98	
F	0.45	0.55	M	0°	10°	



GOOD-ARK Electronics

Marking Outline



Part Name: SSF2300P

1. P/N Mark: .2300.

Revision History

Version	Date	Major Changes
Rev.A	2025.07.08	Official Release



GOOD-ARK Flectronics

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